Advance Information

Hybrid Power Module

Integrated Power Stage for 230 VAC Motor Drive

This VersaPower™ module integrates a 3-phase inverter, 3-phase rectifier, brake, and temperature sense in a single convenient package. It is designed for 1.0 hp general purpose 3-phase induction motor drive applications. The inverter incorporates advanced insulated gate bipolar transistors (IGBT) with integrated ESD protection Gate-Emitter zener diodes and ultrafast soft (UFS) free-wheeling diodes to give optimum performance. The solderable top connector pins are designed for easy interfacing to the user's control board.

- Short Circuit Rated 10 μs @ 125°C, 400 V
- Pin-to-Baseplate Isolation Exceeds 2500 Vac (rms)
- Compact Package Outline
- · Access to Positive and Negative DC Bus
- Independent Brake Circuit Connections
- · UL Recognition Pending
- Visit our website at http://www.mot-sps.com/tsg/

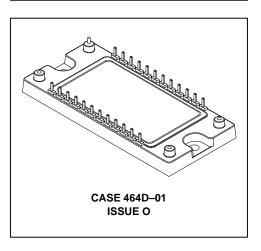
ORDERING INFORMATION

Device	Voltage	Current	Equivalent
	Rating	Rating	Horsepower
XHPM7A10E60DC3	600	10	1.0

MHPM7A10E60DC3

Motorola Preferred Device

10 AMP, 600 VOLT HYBRID POWER MODULE



MAXIMUM DEVICE RATINGS (T_J = 25°C unless otherwise noted)

Rating	Symbol	Value	Unit	
Repetitive Peak Input Rectifier Reverse Voltage (T _J = 25°C to 150°C)	V _{RRM}	900	V	
IGBT Reverse Voltage	VCES	600	V	
Gate-Emitter Voltage	V _{GES}	±20	V	
Continuous IGBT Collector Current (T _C = 80°C)	I _{Cmax}	10	А	
Repetitive Peak IGBT Collector Current (1)	I _{C(pk)}	20	А	
Continuous Free–Wheeling Diode Current (T _C = 25°C)	I _{Fmax}	10	А	
Continuous Free–Wheeling Diode Current (T _C = 80°C)	I _{F80}	6.8	А	
Repetitive Peak Free–Wheeling Diode Current (1)	I _{F(pk)}	20	А	
Average Converter Output Current (Peak-to-Average ratio of 10, T _C = 95°C)	l _{Omax}	20	А	
IGBT Power Dissipation per die (T _C = 95°C)	PD	17	W	
Free–Wheeling Diode Power Dissipation per die (T _C = 95°C)	PD	9.0	W	
Junction Temperature Range	TJ	-40 to +150	°C	
Short Circuit Duration (V _{CE} = 400 V, T _J = 125°C)	t _{SC}	10	μs	
Isolation Voltage, pin to baseplate	V _{ISO}	2500		
Operating Case Temperature Range	T _C	-40 to +95	°C	
Storage Temperature Range	T _{stg}	-40 to +125	°C	
Mounting Torque — Heat Sink Mounting Holes	_	12	lb-in	

⁽¹⁾ 1.0 ms = 1.0% duty cycle

Preferred devices are Motorola recommended choices for future use and best overall value.

This document contains information on a new product. Specifications and information herein are subject to change without notice.

VersaPower is a trademark of Motorola, Inc.





MHPM7A10E60DC3

ELECTRICAL CHARACTERISTICS ($T_J = 25^{\circ}C$ unless otherwise noted)

Characteristic	Symbol	Min	Тур	Max	Unit
DC AND SMALL SIGNAL CHARACTERISTICS					
Input Rectifier Forward Voltage (I _F = 10 A)	٧F	_	0.97	1.2	V
Gate-Emitter Leakage Current (V _{CE} = 0 V, V _{GE} = ±20 V)	IGES	_	_	±50	μΑ
Collector–Emitter Leakage Current (V _{CE} = 600 V, V _{GE} = 0 V)	ICES	_	5.0	100	μΑ
Gate–Emitter Threshold Voltage (V _{CE} = V _{GE} , I _C = 1.0 mA)	V _{GE(th)}	4.0	6.0	8.0	V
Collector–Emitter Breakdown Voltage (I _C = 10 mA, V _{GE} = 0 V)	V(BR)CES	600	_	_	V
Collector–Emitter Saturation Voltage (I _C = I _{Cmax} , V _{GE} = 15 V)	V _{CE(sat)}	_	2.0	2.4	V
Free–Wheeling Diode Forward Voltage (I _F = I _{Fmax} , V _{GE} = 0 V)	٧ _F	1.7	2.0	2.3	V
Input Capacitance (V _{GE} = 0 V, V _{CE} = 25 V, f = 1.0 MHz)	C _{ies}	_	1020	_	pF
Input Gate Charge (V _{CE} = 300 V, I _C = I _{Cmax} , V _{GE} = 15 V)	QT	_	57	_	nC
THERMAL CHARACTERISTICS, EACH DIE	•	•	•		•
Thermal Resistance — IGBT	$R_{ heta$ JC	_	2.6	3.2	°C/W
Thermal Resistance — Free–Wheeling (Fast Soft) Diode	$R_{ heta$ JC	_	4.8	6.0	°C/W
Thermal Resistance — Input Rectifier	$R_{ heta$ JC	_	3.4	4.2	°C/W
TEMPERATURE SENSE DIODE	•		•		
Forward Voltage (@ I _F = 1.0 mA)	VF	2.388	2.418	2.448	V
Forward Voltage Temperature Coefficient (@ I _F = 1.0 mA)	TC _{VF}	_	-7.404	_	mV/°C

TYPICAL CHARACTERISTICS

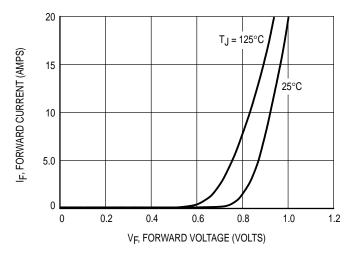


Figure 1. Forward Characteristics — Input Rectifier

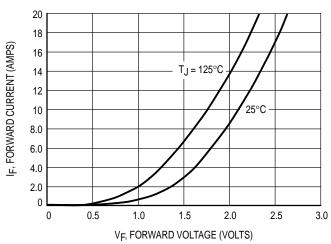


Figure 2. Forward Characteristics — Free–Wheeling Diode

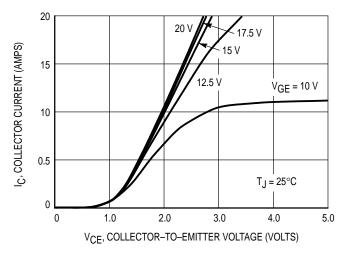


Figure 3. Forward Characteristics, T_J = 25°C

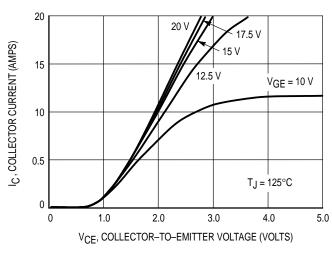


Figure 4. Forward Characteristics, T_J = 125°C

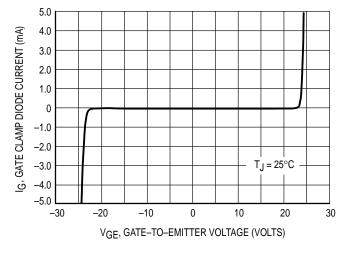


Figure 5. Gate-Emitter Zener Diode Clamp Characteristic

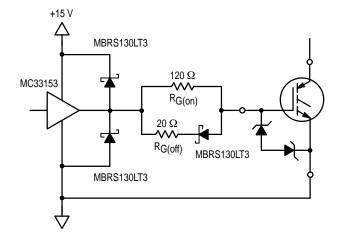
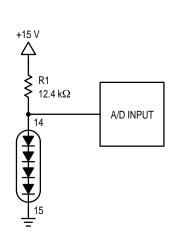


Figure 6. Recommended Gate Drive Circuit

TYPICAL CHARACTERISTICS



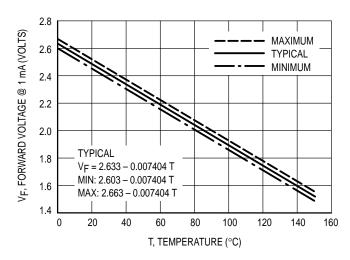


Figure 7. Recommended Temperature Sense Bias Circuit

Figure 8. BAV99LT1 Temperature Sense Diode Performance: $V_F = 2.633 - 7.404E-3 T_C$

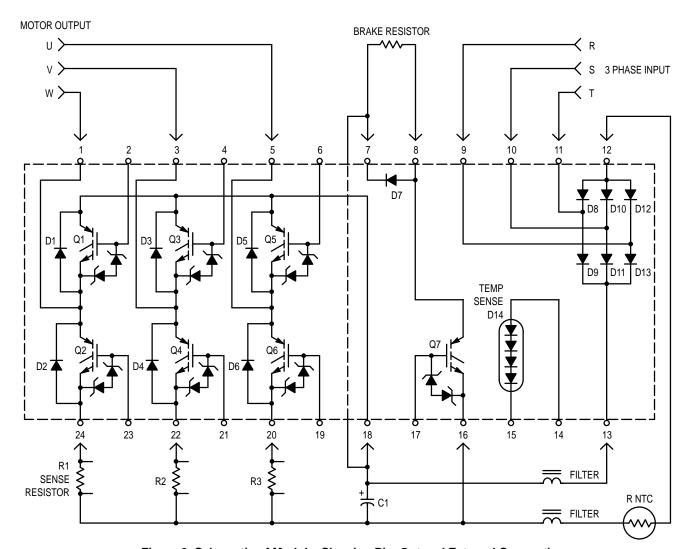
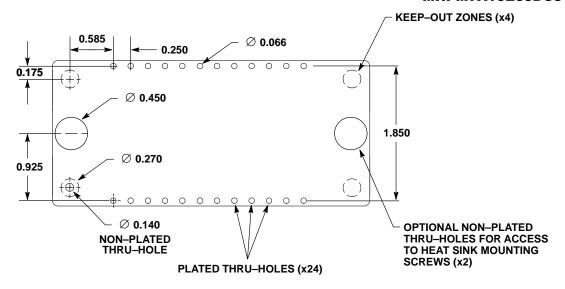


Figure 9. Schematic of Module, Showing Pin-Out and External Connections

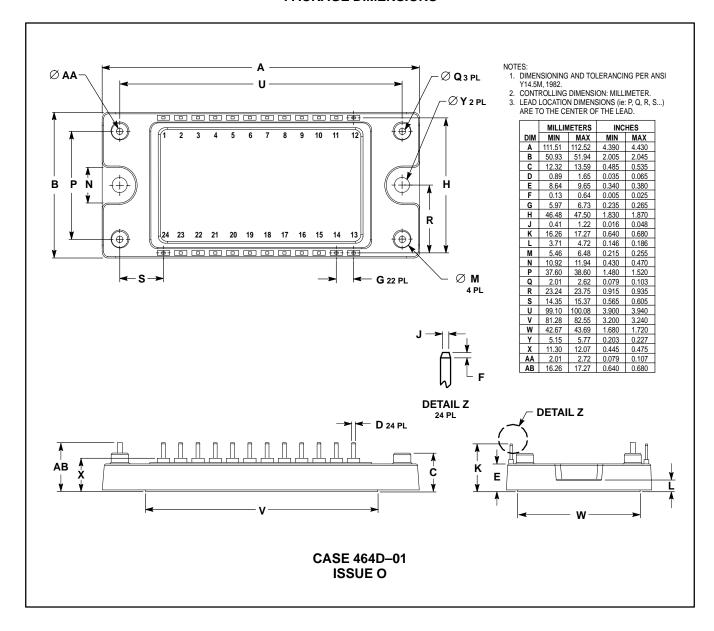


NOTES:

- Package is symmetrical, except for a polarizing plastic post near pin 1, indicated by a non-plated thru-hole in the footprint.
- 2. Dimension of plated thru-holes indicates finished hole size after plating.
- 3. Access holes for mounting screws may or may not be necessary depending on assembly plan for finished product.

Figure 10. Package Footprint (Dimensions in Inches)

PACKAGE DIMENSIONS



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How to reach us:

USA/EUROPE/Locations Not Listed: Motorola Literature Distribution; P.O. Box 5405, Denver, Colorado 80217. 1–303–675–2140 or 1–800–441–2447

JAPAN: Nippon Motorola Ltd.; SPD, Strategic Planning Office, 141, 4–32–1 Nishi–Gotanda, Shinagawa–ku, Tokyo, Japan. 81–3–5487–8488

Customer Focus Center: 1-800-521-6274

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